Unit: mm

TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

1SS422

High-Speed Switching Applications

Low forward voltage VF = 0.23 V (typ.)@IF = 5 mA

• Small package suitable for mounting on a small space

Absolute Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse voltage	V_{RM}	35	V
Reverse voltage	V _R	30	V
Maximum (peak) forward current	I _{FM}	200*	mA
Average forward current	Io	100*	mA
Surge current (10 ms)	I _{FSM}	1*	Α
Power dissipation	Р	100*	mW
Junction temperature	Tj	125	°C
Storage temperature range	T _{stg}	-55~125	°C
Operating temperature range	T _{opr}	-40~100	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

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Weight: 0.0024 g (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

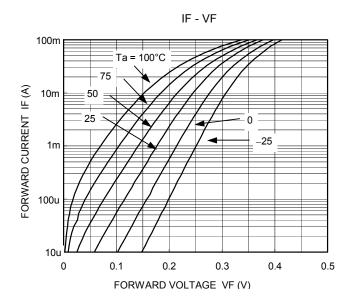
*: This is the absolute maximum rating for a single diode . Where two diodes are used, the absolute maximum rating per diode is 75% that for the single diode.

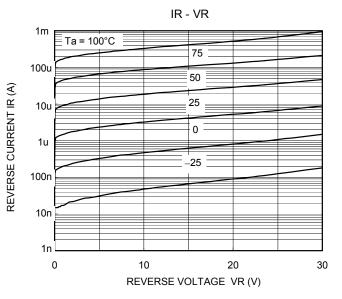
Electrical Characteristics (Ta = 25°C)

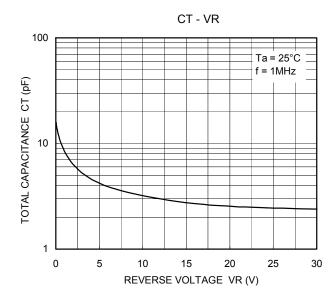
Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward voltage	V _{F (1)}	I _F = 1 mA	_	0.18	_	V
	V _{F (2)}	I _F = 5 mA	_	0.23	_	
	V _{F (3)}	I _F = 100 mA	-	0.38	0.5	
Reverse current $ \frac{ I_{R (1)} }{ I_{R (2)} } $	I _{R (1)}	V _R = 10 V	-	_	20	μА
	I _{R (2)}	V _R = 30 V	_	_	50	
Total capacitance (between Cathode and Anode)	C _T	V _R = 0, f = 1 MH _z	_	15	_	pF

Marking









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20070701-EN GENERAL

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